

Section VIII: SPICE Model Parameters

This is a secure document. Please copy this code from the SPICE model PDF file on our website (http://www.genesicsemi.com/images/hit_sic/baredie/sjt/GA05JT12-CAL_SPICE.pdf) into LTSPICE (version 4) software for simulation of the GA05JT12-CAL.

```
* MODEL OF GeneSiC Semiconductor Inc.  
*  
* $Revision: 2.1 $  
* $Date: 29-JAN-2015 $  
*  
* GeneSiC Semiconductor Inc.  
* 43670 Trade Center Place Ste. 155  
* Dulles, VA 20166  
*  
* COPYRIGHT (C) 2015 GeneSiC Semiconductor Inc.  
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*  
* These models are provided "AS IS, WHERE IS, AND WITH NO WARRANTY  
* OF ANY KIND EITHER EXPRESSED OR IMPLIED, INCLUDING BUT NOT LIMITED  
* TO ANY IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A  
* PARTICULAR PURPOSE."  
* Models accurate up to 2 times rated drain current.  
*.model GA05JT12 NPN  
+ IS 9.8338E-48  
+ ISE 1.0733E-26  
+ EG 3.23  
+ BF 92  
+ BR 0.55  
+ IKF 5000  
+ NF 1  
+ NE 2  
+ RB 10.49  
+ IRB 0.002  
+ RBM 0.32  
+ RE 0.003  
+ RC 0.18  
+ CJC 230E-12  
+ VJC 3.438  
+ MJC 0.498  
+ CJE 568E-12  
+ VJE 2.862  
+ MJE 0.458  
+ XTI 3  
+ XTB -1.5  
+ TRC1 6.5E-3  
+ VCEO 1200  
+ ICRATING 5  
+ MFG GeneSiC_Semiconductor  
*  
* End of GA05JT12 SPICE Model
```